

Form PTO-1449				ATTY. DOCKET NO. 3430-0200P		APPLICATION NO. NEW 10/757521			
INFORMATION DISCLOSURE CITATION IN AN APPLICATION (Use several sheets if necessary)				APPLICANT Woong-Kwon KIM					
				FILING DATE January 15, 2003		GROUP Unassigned			
U.S. PATENT DOCUMENTS									
EXAMINER INITIAL	DOCUMENT NUMBER	Kind	DATE	NAME	CLASS	SUB CLASS	FILING DATE IF APPROPRIATE		
a	US 5,994,721	A	1999-11-30	ZHONG et al					
	US 6,104,510	A		KASHIWAZAKI et al					
	US 6,104,459	A	2000-08-15	OIKE et al					
	US 5,724,107	A	1998-03-03	NISHIKAWA et al					
	US 6,211,928	B1	2001-04-03	OH et al					
	US 6,221,543	B1	2001-04-24	GUEHLER et al					
	US 5,994,721	A	1999-11-30	ZHONG et al					
	US 6,162,510	A	2000-12-19	KASHIWAZAKI et al					
	US 6,297,862	B1	2001-10-02	MURADE					
	US 6,166,786	A	2000-12-26	OHKUBO et al					
	US 6,327,006	B1	2001-12-04	SATO et al					
	US 6,281,955	B1	2001-08-28	MIDORIKAWA et al					
a	US 6,111,623	A	2000-08-29	SATO					
FOREIGN PATENT DOCUMENTS									
	Office	DOCUMENT NUMBER	Kind	DATE	COUNTRY	CLASS	SUB CLASS	TRANSLATION	
								YES	NO
OTHER DOCUMENTS (Include Name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.) date, page(s), volume-issue number(s), publisher, city and/or country where published.)									
a	Pichon et al; "Low temperature unhydrogennated in-situ doped polysilicon thin film transistors: Toward a technology for flat panel displays"; Thin Solid Film, Vol. 296, pages 133-136; 1997.								
EXAMINER					DATE CONSIDERED				
Hoan Nguyen					8/31/04				
EXAMINER: Initial if citation considered, whether or not citation is in conformance with M.P.E.P. 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.									